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Kind regards,

Team Nexperia



BCV64B PNP general-purpose double transistor Rev. 4 – 2 August 2010

Product data sheet

1. Product profile

1.1 General description

PNP general-purpose double transistor in a small SOT143B Surface-Mounted Device (SMD) plastic package.

Table 1.Product overview

Type number	Package		PNP complement	
	NXP	JEITA		
BCV64B	SOT143B	-	BCV63B	

1.2 Features and benefits

- Low current (max. 100 mA)
- Low voltage (max. 30 V and 6 V)
- AEC-Q101 qualified
- Small SMD plastic package

1.3 Applications

- General-purpose switching and amplification
- For use in Schmitt trigger applications

1.4 Quick reference data

Table 2. Quick reference data

	quient rener entre auta					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per trans	istor					
I _C	collector current		-	-	-100	mA
Transisto	or TR1					
V _{CEO}	collector-emitter voltage	open base	-	-	-30	V
h _{FE}	DC current gain	V _{CE} = –5 mV; I _C = –2 mA	220	-	475	
Transisto	or TR2					
V _{CEO}	collector-emitter voltage	open base	-	-	-6	V
h _{FE}	DC current gain	$V_{CE} = -700 \text{ V};$ $I_{C} = -2 \text{ mA}$	[1] 220	-	475	

[1] Due to matched dies, h_{FE} values for TR2 are the same as for TR1.



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PNP general-purpose double transistor

2. Pinning information

Table 3.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	collector TR2 and base TR1		
2	collector TR1		
3	emitter TR1 and TR2		
4	base TR2		

3. Ordering information

Table 4. Orderi	ng informa	tion	
Type number	Package		
	Name	Description	Version
BCV64B	-	plastic surface-mounted package; 4 leads	SOT143B

4. Marking

Table 5. Marking codes	
Type number	Marking code ^[1]
BCV64B	*C6
[1] * = -: made in Hong Kong	

- * = p: made in Hong Kong
- * = t: made in Malaysia
- * = W: made in China

5. Limiting values

Table 6. In accorda	Limiting values ance with the Absolute Maximum	Rating System (IEC	60134).		
Symbol	Parameter	Conditions	Min	Max	Unit
Per trans	istor				
V_{EBO}	emitter-base voltage	open collector	-	-6	V
I _C	collector current		-	-100	mA
I _{CM}	peak collector current		-	-200	mA
I _B	base current		-	-100	mA
Transisto	or TR1				
V _{CBO}	collector-base voltage	open emitter	-	-30	V
V _{CEO}	collector-emitter voltage	open base	-	-30	V
Transisto	or TR2				
V _{CBO}	collector-base voltage	open emitter	-	-6	V
V _{CEO}	collector-emitter voltage	open base	-	-6	V
Per devic	;e				
P _{tot}	total power dissipation	$T_{amb} \leq 25 ~^{\circ}C$	<u>[1]</u> _	250	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB).

6. Thermal characteristics

Table 7.	Thermal characteristics
----------	-------------------------

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	<u>[1]</u> -	-	500	K/W

[1] Device mounted on an FR4 PCB.

7. Characteristics

Table 8. Characteristics

 $T_i = 25 \ ^{\circ}C$ unless otherwise specified.

Per transistor I_{CBO} collector-base cut-off current $V_{CB} = -30 \text{ V}; I_E = 0 \text{ A}$ $V_{CB} = -30 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 ^{\circ}\text{C}$ -	-15 -5	nA
cut-off current $V_{CB} = -30 \text{ V}; \text{ I}_E = 0 \text{ A}; - T_j = 150 \text{ °C}$		
$v_{CB} = -30 \text{ v}, n_E = 0 \text{ A}, T_j = 150 \text{ °C}$	-5	
		μA
$\label{eq:VCEsat} \begin{array}{c} \text{Collector-emitter} & \text{I}_{C} = -10 \text{ mA}; \\ \text{saturation voltage} & \text{I}_{B} = -0.5 \text{ mA} \end{array} \qquad -75$	-300	mV
V_{BEsat} base-emitter $I_{C} = -10$ mA; [2]700 saturation voltage $I_{B} = -0.5$ mA	-	mV
Transistor TR1		
h _{FE} DC current gain $V_{CE} = -5 V$; 220 - $I_C = -2 mA$	475	
	-650	mV
V_{BEsat} base-emitter $I_{C} = -100 \text{ mA};$ [2]850 saturation voltage $I_{B} = -5 \text{ mA}$	-	mV
V_{BE} base-emitter voltage I_{C} = -2 mA; [3] -600 -650 V_{CE} = -5 V	-750	mV
$I_{C} = -10 \text{ mA};$ [3] $V_{CE} = -5 \text{ V}$	-820	mV
f_{T} transition frequency V_{CE} = –5 V; 100 - I_{C} = –10 mA; f = 100 MHz	-	MHz
$ \begin{array}{cc} C_c & \mbox{ collector capacitance } & V_{CB} = -10 \ V; & - & 4 \\ & I_E = i_e = 0 \ A; \\ & f = 1 \ MHz \end{array} $	-	pF
Transistor TR2		
h_{FE} DC current gain $V_{CE} = -700 \text{ mV};$ [1] 220 - $I_C = -2 \text{ mA}$	475	
V_{CEsat} collector-emitter $I_{C} = -100 \text{ mA};$ 250 saturation voltage $I_{B} = -5 \text{ mA}$	-	mV
V_{BE} base-emitter voltage $I_C = -2 \text{ mA};$ [3]700 $V_{CE} = -700 \text{ mV}$	-	mV

[1] Due to matched dies, h_{FE} values for TR2 are the same as for TR1.

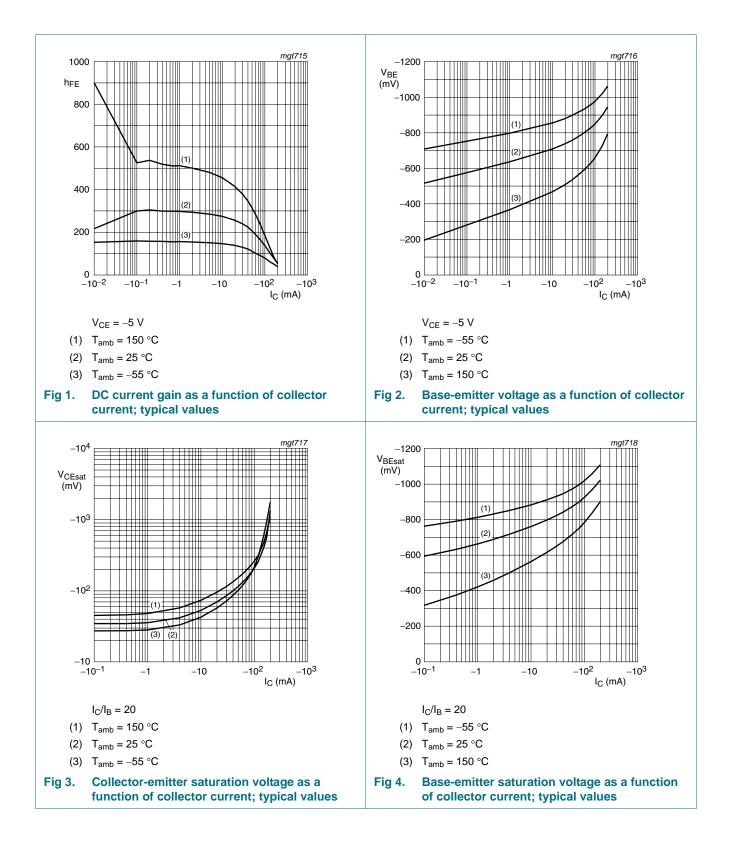
[2] V_{BEsat} decreases by about 1.7 mV/K with increasing temperature.

[3] V_{BE} decreases by about 2 mV/K with increasing temperature.

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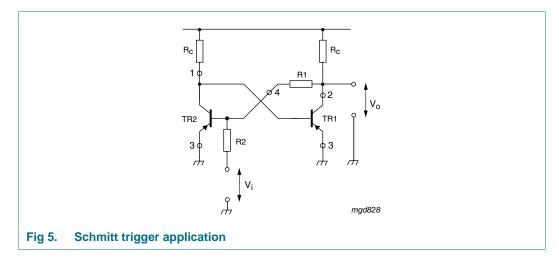
BCV64B

PNP general-purpose double transistor



BCV64B

8. Application information

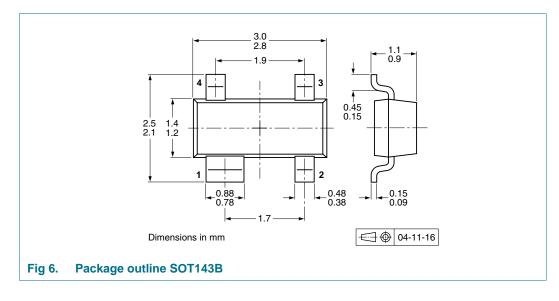


9. Test information

9.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

10. Package outline



11. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

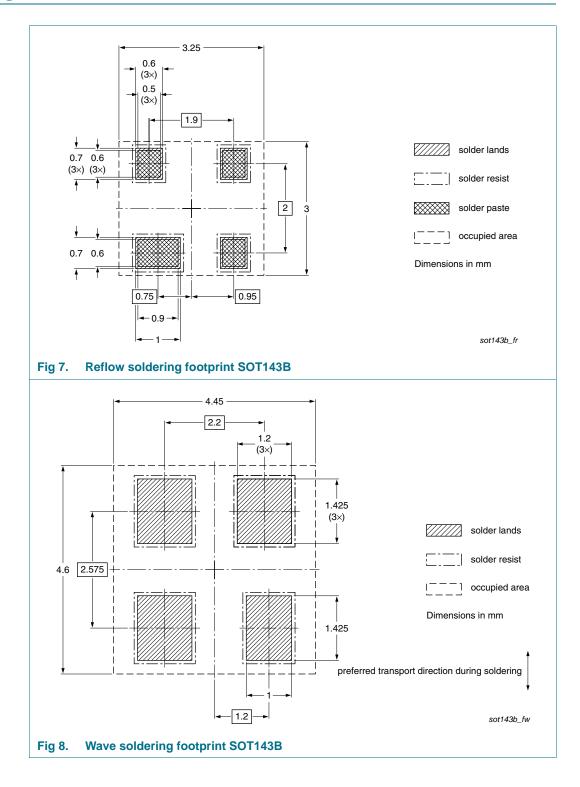
Type number	Package	ge Description Packing quan		quantity
			3000	10000
BCV64B	SOT143B	4 mm pitch, 8 mm tape and reel	-215	-235

[1] For further information and the availability of packing methods, see <u>Section 15</u>.

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12. Soldering



13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BCV64B v.4	20100802	Product data sheet	-	BCV64B_3		
Modifications:		of this data sheet has been of NXP Semiconductors.	redesigned to comply w	vith the new identit		
	 Legal texts 	have been adapted to the r	new company name whe	ere appropriate.		
	Section 1 "	 Section 1 "Product profile": amended. 				
	Section 3 "	Ordering information": adde	d.			
	 <u>Section 4 "Marking"</u>: updated. 					
	• <u>Figure 1</u> , <u>2</u> , <u>3</u> and <u>4</u> : added.					
	 Section 8 "Application information": added. 					
	 <u>Section 9 "Test information"</u>: added. 					
	 Figure 6: superseded by minimized package outline drawing. 					
	Section 11	"Packing information": adde	ed.			
	Section 12	"Soldering": added.				
	 Section 14 	"Legal information": update	d.			
BCV64B_3	19990521	Product specification	-	BCV64_CNV_2		
BCV64_CNV_2	19970310	Product specification	_	-		

14. Legal information

14.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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Date of release: 2 August 2010 Document identifier: BCV64B

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